

CHCRUS

This is the accepted manuscript made available via CHORUS. The article has been published as:

Computation of the Correlated Metal-Insulator Transition in Vanadium Dioxide from First Principles Huihuo Zheng and Lucas K. Wagner

Phys. Rev. Lett. **114**, 176401 — Published 27 April 2015 DOI: 10.1103/PhysRevLett.114.176401

Computation of the correlated metal-insulator transition in vanadium dioxide from first principles

Huihuo Zheng and Lucas K. Wagner^{*}

Department of Physics, University of Illinois at Urbana-Champaign Urbana, IL 61801-3080, USA

Vanadium dioxide(VO₂) is a paradigmatic example of a strongly correlated system that undergoes a metal-insulator transition at a structural phase transition. To date, this transition has necessitated significant post-hoc adjustments to theory in order to be described properly. Here we report standard state-of-the-art first principles quantum Monte Carlo (QMC) calculations of the structural dependence of the properties of VO₂. Using this technique, we simulate the interactions between electrons explicitly, which allows for the metal-insulator transition to naturally emerge, importantly without *ad-hoc* adjustments. The QMC calculations show that the structural transition directly causes the metal-insulator transition and a change in the coupling of vanadium spins. This change in the spin coupling results in a prediction of a momentum-independent magnetic excitation in the insulating state. While two-body correlations are important to set the stage for this transition, they do not change significantly when VO₂ becomes an insulator. These results show that it is now possible to account for electron correlations in a quantitatively accurate way that is also specific to materials.

Systems of strongly correlated electrons at the border between a metal-insulator transition can result in a variety of unique and technologically useful behavior, such as high-temperature superconductivity[1] and collossal magnetoresistance[2]. In vanadium dioxide (VO_2) , the metal-insulator transition (MIT) occurs at T = 340K [3], at which the conductivity decreases by more than 4 orders of magnitude. This MIT is accompanied by a structural change from rutile $(P4_2/mnm)$ to monoclinic $(P2_1/c)$ [4], as well as a transition in the magnetic susceptibility from a paramagnet-like Curie-Weiss law to a temperature-independent form. In the rutile phase, the vanadium atoms are located at the centers of octahedra formed by the oxygen atoms; chains of equidistant vanadium atoms lie along the c axis ([001]). In the low-temperature monoclinic phase, vanadium atoms shift from the centers of the oxygen octahedra and form a zigzag pattern consisting of V dimers. It is a long-standing question whether the MIT is primarily caused by the structural change that doubles the unit cell (Peierls distortion), or by correlation effects that drive the system to become insulating [5-7], or potentially some mixture of the two.

The metal-insulator transition in VO₂ is unusually challenging to describe. Standard density functional theory (DFT) [8, 9] obtains metallic states for both structures, while corrections based on an effective Hubbard U[9, 10] or hybrid functionals[11] often obtain insulating states for both structures. Similarly, DFT+DMFT[7, 12, 13] and DFT+GW[14–16] calculations indicate that how the correlation is treated changes the calculated properties dramatically. Therefore, while they are descriptive and valuable techniques, their reliability is uncertain in a predictive capacity. This issue is a severe constraint for the design and study of correlated electron systems.

In this study, we use the explicitly correlated fixednode diffusion quantum Monte Carlo (FN-DMC) [17]



FIG. 1. FN-DMC energies of VO₂ with trial wave functions from DFT of different hybrid functionals. All the energies are relative to monoclinic AFM state: -2830.836(2)eV.

to investigate the electronic structures of the rutile and monoclinic VO_2 from first principles. FN-DMC has been shown to be a highly accurate method on other transition metal oxides [18, 19]. In this method, one explicitly samples many-body electronic configurations using Coulomb's law for interactions, which allows for the description of correlation effects without effective parameters. We show that FN-DMC correctly characterizes the electronic structure and magnetic response of VO_2 in the two phases. Our calculations provide quantitative microscopic details of the structure-dependent spin couplings between vanadium atoms. It clearly reveals how the structural distortion changes the interatomic hybridization between vanadium and oxygen, which results in a significant change of the superexchange magnetic coupling between vanadium atoms. Monoclinic VO_2 is in a non-magnetic singlet state consisting of spin dimers due to strong intradimer coupling. The calculations contain a singlet-triplet spin excitation of 123(6) eV in mon-



FIG. 2. (Color online) FN-DMC energetic results: (a) per VO₂ unit for different magnetically ordered states, spin-unpolarized, ferromagnetic (FM), and antiferromagnetic [AFM and AFM (intra)]. Energies are referenced to AFM monoclinic VO₂.(b) Optical gaps for various states. (c) Spin density for various states.

oclinic VO_2 , which can be verified in experiment to test the predictive power of this method.

The calculations were performed as follows. The crystal structure of the rutile and monoclinic phases were taken from experiment [21]. DFT calculations were performed using the CRYSTAL package, with initial spin configurations set to aligned, anti-aligned, or unpolarized vanadium atoms. Different exchange-correlation functionals with varying levels of Hartree-Fock exchange were used:

$$E_{xc} = (1-p)E_x^{PBE} + pE_x^{HF} + E_c^{PBE}$$
(1)

where E_x^{PBE} and E_c^{PBE} are the Perdew-Burke-Ernzerhof (PBE) exchange and correlation functionals respectively. The simulations were performed on a supercell including 16 VO₂ formula units with 400 valence electrons. A $4 \times 4 \times 8$ Monkhorst-Pack k-grid was chosen for sampling the first Brillouin zone of the simulation cell. A Burkatzki-Filippi-Dolg (BFD) pseudopotential [22, 23] was used to represent the He core in oxygen and Ne core in vanadium. The band structure obtained using the BFD pseudopotential shows good agreement with the all-electron DFT calculation [24] (using PBE functional).



FIG. 3. Temperature dependence of magnetic susceptibility obtained by Ising model simulation on VO₂ lattice, with magnetic coupling from FN-DMC compared to results from Zylbersztejn[6] and Kosuge[20]. There has been an overall scale applied on the data, and the transition temperature is indicated by the verticle dashed line.

The result of the DFT calculations is a set of Slater determinants made of Kohn-Sham orbitals that have varying transition metal-oxygen hybridization and spin orders. A Jastrow correlation factor was then added to these Slater determinants as the trial wave functions for quantum Monte Carlo calculations [25]. Total energies were averaged over twisted boundary conditions and finite size errors were checked to ensure that they are negligible (see Supplementary Information). The fixed-node error in FN-DMC was checked by comparing the energetic results from different trial wave functions from DFT calculations with different p in Eqn 1. The trial wave functions corresponding to the 25% Hartree-Fock mixing (PBE0 functional [26]) produce the minimum FN-DMC energy (Fig 1). The behavior in VO_2 is commonly seen in other transition metal oxides [27]. Thus, all our FN-DMC results in the main manuscript were produced using 25% mixing. The gap was determined by promoting an electron from the highest occupied band to the lowest unoccupied orbital in the Slater determinant, then using that determinant as a trial function for FN-DMC.

The energetic results of the quantum Monte Carlo calculations are summarized in Fig 2. Both the rutile and monoclinic structures have lowest energy with antiferromagnetic ordering of the spins. The unpolarized trial function has sufficiently high energy to remove it from consideration of the low energy physics. The energy difference between the ferromagnetic and antiferromagnetic orderings changes from 24(6) meV to 123(6) meV from the rutile to monoclinic structure. The energy difference between the lowest energy spin orderings for rutile and monoclinic is 10(6) meV, which is within statistical uncertainty of zero. The latent heat is 44.2(3) meV[28]; the small descrepancy may be due to either finite temperature or nuclear quantum effects, or fixed node error. In the monoclinic structure, the vanadium atoms are dimerized, which allows for a type of magnetic ordering in which the intra-dimer vanadium dimers are aligned. This ordering increases the energy by 13(6) meV.

The lowest energy wave functions all have magnetic moments on the vanadium atoms close to 1 Bohr magneton. In the rutile structure, the spins are coupled with a small superexchange energy along the c axis. In the monoclinic structure, the spins are coupled strongly within the vanadium dimers and weakly between them. The spin coupling within the dimers should give rise to a spin excitation with little dispersion at approximately 123(6) meV, which could potentially be observed with neutron spectroscopy. This excitation has been proposed in the past by Mott[29]; our results here provide a precise number for this excitation.

To study whether the magnetic behavior from the energies in Fig 2 are consistent with experiment, we make a simple Ising model. In our model, the spins are on vanadium sites, and we only consider couplings between adjacent sites: $(1)J_1$ – intra-dimer coupling; (2) J_2 – interdimer coupling; (3) J_{int} – nearest inter-chain coupling (see Fig. 3). We assume that the energy for a magnetic state takes the following form,

$$E = J_1 \sum_{\text{intradimer} < i,j>} \sigma_i \sigma_j + J_2 \sum_{\text{interdimer} < i,j>} \sigma_i \sigma_j + J_{\text{int}} \sum_{\text{interchain} < i,j>} \sigma_i \sigma_j + E_0.$$
(2)

We fit J_1 and J_2 to the energetic results of the FM, AFM, and AFM(intra) orderings. For the monoclinic structure, $J_1 = 123$ meV, $J_2 = 13$ meV, while for the rutile structure $J_1 = J_2 = 12$ meV. Since we did not compute the inter-chain coupling strength J_{int} , we set it to be 2.5 meV which is reasonably small compared to the intra-chain coupling. The result is not sensitive to the inter-chain coupling as long as it is small. We then perform a Monte Carlo simulation is on a $10 \times 10 \times 10$ super cell, in which the finite size effect has been checked to be small. The results are presented in Fig 3. The Curie-Weiss behavior of the magnetic susceptibility above the transition temperature is reproduced very well, while the flat susceptibility below the transition is also reproduced.

Moving to the gap properties (Fig 2b), the gap of the low-energy AFM ordering in the rutile structure is zero, while the gap in the monoclinic is 0.8(1) eV. This compares favorably to experiment, which have gaps of zero and 0.6-0.7 eV[30]. Meanwhile, in the higher energy FM ordering, the monoclinic structure has a minimal gap of 0.42(7) eV and the rutile structure has a gap of 0.0(1)eV, both in the spin-majority channel. If there are not unpaired electrons on the vanadium atoms, then the gap is zero.

From the above energy considerations, a few things become clear about the results of the FN-DMC calculation. The gap formation is not due to a particular spin orientation, so the transition is not of Slater type. However, it is dependent on the formation of unpaired electrons on the vanadium atoms. These behaviors might lead one to suspect that the transition is of Mott type, since the gap in the monoclinic structure is a $d \rightarrow d$ transition. In the classic Mott-Hubbard model, the metal-insulator transition is a function of U/t, where U is the on-site repulsion and t is the site-to-site hopping.

To make the physics more clear, we connect the detailed quantum results to an approximate low-energy Hubbard-like model. We define the V sites and O sites by the Voronoi polyhedra surrounding the nuclei. For a given sample in the FN-DMC calculation, we evaluate the number of up spins n_i^{\uparrow} and the number of down spins n_i^{\downarrow} on a given site *i*. We then histogram the joint probability to obtain a set of functions $\rho_{i,j,\sigma_i,\sigma_j}(n_i^{\sigma_i}, n_j^{\sigma_j})$, where i, j are site indices and σ_i, σ_j are spin indices. The connection to t and U are made through covariances of these number operators. t is connected to the covariance in the total number of electrons on a site $i, n_i = n_i^{\uparrow} + n_i^{\downarrow}$ with site j: $\langle (n_i - \langle n_i \rangle)(n_j - \langle n_j \rangle) \rangle$. If this charge covariance is large, then the two sites share electrons and thus t between those two sites is large. U/\bar{t} , where \bar{t} is the average hopping, is connected to the covariances in the number of up electrons and down electrons on a given site: $\langle (n_i^{\uparrow} - \langle n_i^{\uparrow} \rangle) (n_i^{\downarrow} - \langle n_i^{\downarrow} \rangle) \rangle$. This quantity, which we term the onsite spin covariance, is zero for Slater determinants and is a measure of the correlation on a given site.

Fig 4a shows the covariances evaluated for the AFM ordering of the two structures of VO₂. The most striking feature is that the charge covariance changes dramatically between the two structures. This feature can also be seen in the charge density in Fig 4c. The dimerization causes a large change in the hybridization between vanadium and oxygen atoms. In particular, the largest hybridization is now not within the dimers, but between the vanadium atoms and the oxygen atoms in the adjacent chain, denoted a_m in Fig 4b. The intra-dimer hybridization is enhanced, and the inter-dimer hybridization is suppressed. There are thus large rearrangements in the effective value of t, although the average value \bar{t} is approximately constant.

On the other hand, the onsite unlike spin covariance does not change within stochastic uncertainties. In Fig 4b, the joint probability function of n_{\uparrow} and n_{\downarrow} averaged over vanadium atoms with a net up spin are shown for both rutile and monoclinic phases. The correlations between up and down electrons are identical within statistical uncertainties in the two structures. Therefore, U/\bar{t} does not change very much between the two structures. A one dimensitional Hubbard model would have $U/\bar{t} \simeq 2.0$ to obtain the unlike spin covariance that we observe, which puts VO₂ in the moderately correlated regime.



FIG. 4. (Color online) Change of V-O hybridizations manifested through: (a) Inter-site charge (n_i) , and unlike-spin $(n_i\uparrow \text{ or } n_i\downarrow)$ covariance quantified as $\langle O_i O_j \rangle - \langle O_i \rangle \langle O_j \rangle$, where O_i is the onsite value of specific physical quantities. The inter-site covariance between a chosen vanadium center and the surrounding atoms is plotted as a function of the inter-atomic distance. (b) Onsite spin-resolved probability distribution on vanadium atoms $-\rho(n_i^{\uparrow}, n_i^{\downarrow})$. (c) Spin and charge density of the rutile and monoclinic VO₂. Figures on the left panel are 3D isosurface plots of spin density, and on the right panel are contour plots of spin and charge density on the [110] plane.

By performing detailed calculations of electron correlations within VO_2 , we have shown that it is possible to describe the metal-insulator transition by simply changing the structure. To obtain the essential physics, it appears that the change in structure is enough to cause the metal-insulator transition. As has been noted before [15], the calculated properties of VO_2 are exceptionally sensitive to the way in which correlation is treated. It is thus a detailed test of a method to describe this transition. Fixed node diffusion quantum Monte Carlo passed this test with rather simple nodal surfaces, which is encouraging for future studies on correlated systems. This method, historically relegated to studies of model systems and very simple *ab-initio* models, can now be applied to *ab-initio* models of correlated electron systems such as VO_2 and other Mott-like systems [18, 19, 31].

From the quantitatively accurate simulations of electron correlations, a simple qualitative picture arises. In both phases, there are net spins on the vanadium atoms with moderate electron-electron interactions compared to the hopping. In the rutile phase, the vanadium oxide chains are intact with large hopping and small superexchange energy and thus the material is a correlated paramagnetic metal. In the monoclinic phase, the dimerization reduces the interdimer hopping, primarily by interchain V-O coupling. The intradimer magnetic coupling increases because of an increase of intradimer V-O coupling. The spins then condense into dimers and a gap forms. This can be viewed as a spin Peierls-like transition.

The results contained in this work, alongside other recent results show that the dream of simulating the many-body quantum problem for real materials to high accuracy is becoming achievable. This accomplishment is a lynchpin for the success of computational design of correlated electron systems, since these calculations can achieve very high accuracy using only the positions of the atoms as input. We have demonstrated that clear predictions for experiment can be made using *ab-initio* quantum Monte Carlo techniques, in particular the value of the singlet-triplet excitation in the spin-dimers of VO₂. If this prediction is verified, then it will be clear that these techniques can provide an important component to correlated electron systems design.

ACKNOWLEDGEMENT

The authors would like to thank David Ceperley for helpful discussions. This work was supported by NSF DMR 12-06242 (LKW) and the Strategic Research Initiative at the University of Illinois (HZ). The computation resources were from Blue Waters (PRAC-jmp), Taub (UIUC NCSA), and Kraken (XSEDE Grant DMR 120042).

- * lkwagner@illinois.edu
- [1] J. W. Lynn, *High Temperature Super Conductivity* (Springer, 1990).
- [2] A. P. Ramirez, Journal of Physics: Condensed Matter 9, 8171 (1997).
- [3] F. J. Morin, Physical Review Letters 3, 34 (1959).
- [4] G. Andersson, Acta chemica Scandinavica 10 (1956).
- [5] J. B. Goodenough, Physical Review 117, 1442 (1960).
- [6] A. Zylbersztejn and N. F. Mott, Physical Review B 11, 4383 (1975).
- [7] A. S. Belozerov, M. A. Korotin, V. I. Anisimov, and A. I. Poteryaev, Physical Review B 85, 045109 (2012).
- [8] V. Eyert, arXiv:cond-mat/0210558 (2002).
- [9] V. Eyert, Physical Review Letters **107**, 016401 (2011).
- [10] M. E. Williams, W. H. Butler, C. K. Mewes, H. Sims, M. Chshiev, and S. K. Sarker, Journal of Applied Physics 105, 07E510 (2009).
- [11] R. Grau-Crespo, H. Wang, and U. Schwingenschlogl, Physical Review B 86, 081101 (2012).
- [12] A. Cavalleri, T. Dekorsy, H. H. W. Chong, J. C. Kieffer, and R. W. Schoenlein, Physical Review B 70, 161102 (2004).
- [13] S. Biermann, A. Poteryaev, A. I. Lichtenstein, and A. Georges, Physical Review Letters 94, 026404 (2005).
- [14] A. Continenza, S. Massidda, and M. Posternak, Physical Review B 60, 15699 (1999).
- [15] M. Gatti, F. Bruneval, V. Olevano, and L. Reining, Physical Review Letters 99, 266402 (2007).

- [16] R. Sakuma, T. Miyake, and F. Aryasetiawan, Journal of Physics-Condensed Matter 21, 064226 (2009).
- [17] W. M. C. Foulkes, L. Mitas, R. J. Needs, and G. Rajagopal, Reviews of Modern Physics 73, 33 (2001).
- [18] J. Kolorenc and L. Mitas, Physical Review Letters 101, 185502 (2008).
- [19] L. K. Wagner and P. Abbamonte, Physical Review B 90, 125129 (2014).
- [20] K. Kosuge, Journal of the Physical Society of Japan 22, 551 (1967).
- [21] Y. Ishiwata, S. Suehiro, M. Hagihala, X. G. Zheng, T. Kawae, O. Morimoto, and Y. Tezuka, Physical Review B 82, 115404 (2010).
- [22] M. Burkatzki, C. Filippi, and M. Dolg, The Journal of Chemical Physics 126, 234105 (2007).
- [23] M. Burkatzki, C. Filippi, and M. Dolg, The Journal of Chemical Physics 129, 164115 (2008).
- [24] "The exciting code," http://exciting-code.org/.
- [25] L. K. Wagner, M. Bajdich, and L. Mitas, Journal of Computational Physics 228, 3390 (2009).
- [26] C. Adamo and V. Barone, The Journal of Chemical Physics 110, 6158 (1999).
- [27] J. Kolorenc, S. Hu, and L. Mitas, Physical Review B 82, 115108 (2010).
- [28] C. N. Berglund and H. J. Guggenheim, Physical Review 185, 1022 (1969).
- [29] N. F. Mott and L. Friedman, Philosophical Magazine 30, 389 (1974).
- [30] S. Shin, S. Suga, M. Taniguchi, M. Fujisawa, H. Kanzaki, A. Fujimori, H. Daimon, Y. Ueda, K. Kosuge, and S. Kachi, Physical Review B 41, 4993 (1990).
- [31] K. Foyevtsova, J. T. Krogel, J. Kim, P. R. C. Kent, E. Dagotto, and F. A. Reboredo, Physical Review X 4, 031003 (2014).